

INFORMATION DISCLOSURE CITATION IN AN APPLICATION

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APPLICANT
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**GROUP
3742**

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Codes - Number - Kind Codes (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation	
						Yes	No
M		JP 2818735	08/21/1998	AT&T CORP.	Corresponds with US Patent 5,397,372	—	x
M		EP 0 216 338 A2	09/20/1988	POLAROID CORPORATION		—	

OTHER ART: (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.
me		"2.1 RF Induced Thermal Plasma Process.", The R&D Review of Toyota CRDL (Toyota central R&D Labs), Volume 29, Number 3, (1994.9), pp. 61-69 and partial English Translation thereof.

EXAMINER

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Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.